

Microelectronics Design

Assignment -1

Member- 1

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2019A3PS0158P

T-5

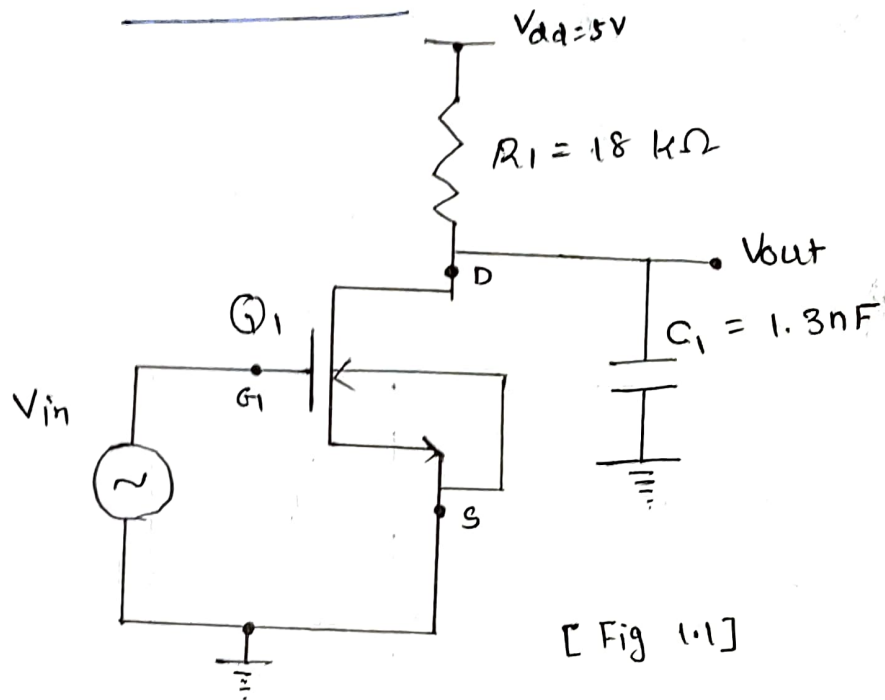
Member- 2

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PROBLEM - 1 :-



Note :- \rightarrow Here input signal amplitude is $1V$, and $V_{ov} = 0.2V$, this small overdrive voltage will not work for such large signal so output signal will be clipped off on positive side

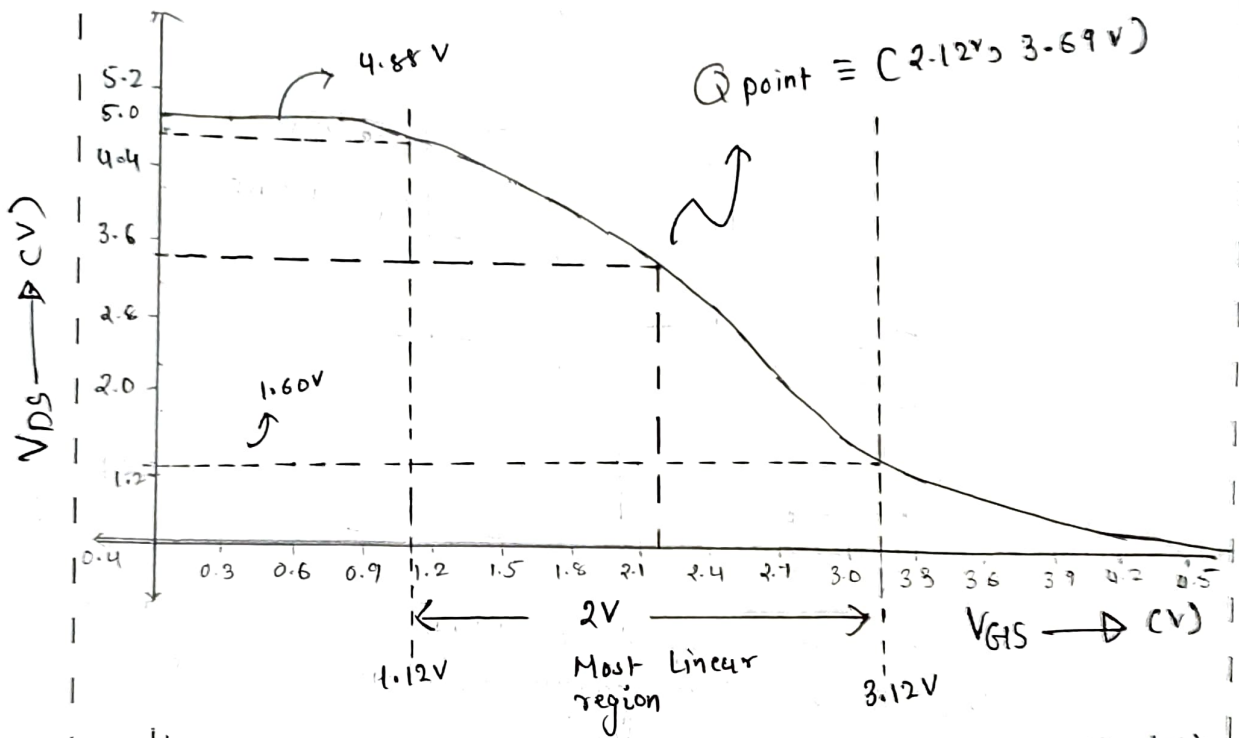
\rightarrow So in calculation, MOSFET to work we will be using modified V_{ov} obtained from VTC (Voltage transfer characteristics).

\rightarrow And further results will be obtained on the basis of this V_{ov} .

\rightarrow Also $1V + 1V = 2V$ swing is too large, so there will be some non-linearity in output swing.

\rightarrow which can be observed by plotting output voltage spectrum, attached at last.

* Voltage transfer characteristics



Note:- Some values may slightly differ with SPICE simulation due to hand-drawing.

⇒ At Q-point (DC bias point) :-

$$V_{GS} = 2.12 \text{ V}$$

$$I_D = 72.77 \text{ }\mu\text{A}$$

$$V_{DS} = 3.69 \text{ V}$$

$$I_D = \frac{V_{DD} - V_{DS}}{R_D} = \frac{5 - 3.69}{18 \times 10^3} = 72.77 \text{ }\mu\text{A}$$

$$V_{th} = 0.669 \text{ V}$$

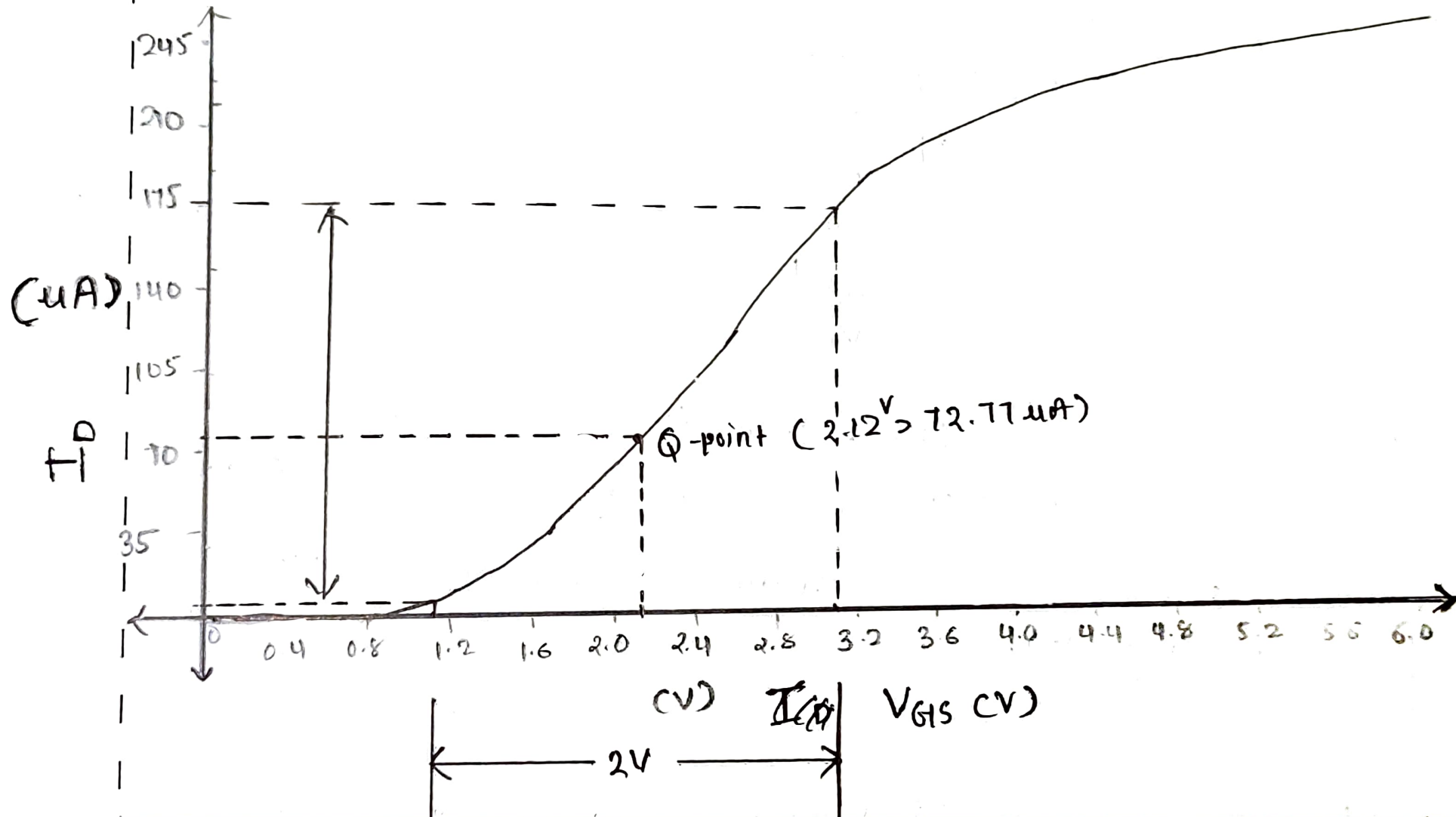
$$V_{ov} = 2.12 - 0.669$$

$$V_{ov} = 1.451 \text{ V}$$

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* Output characteristics :-



$$g_m = \frac{2I_D}{V_{ov}}$$

$$I_D (\text{simulated}) = 12.6513 \mu\text{A}$$

$$V_{ov} = 2.12658 - 0.669$$

$$(V_{gs}) - (V_{th})$$

$$V_{ov} = 1.4579 \text{ V}$$

$$g_m = 0.099 \text{ mA/V}$$

$$A_v (\text{simulated}) = -1.7500$$

$$A_v (\text{calculated}) = -g_m R_D$$

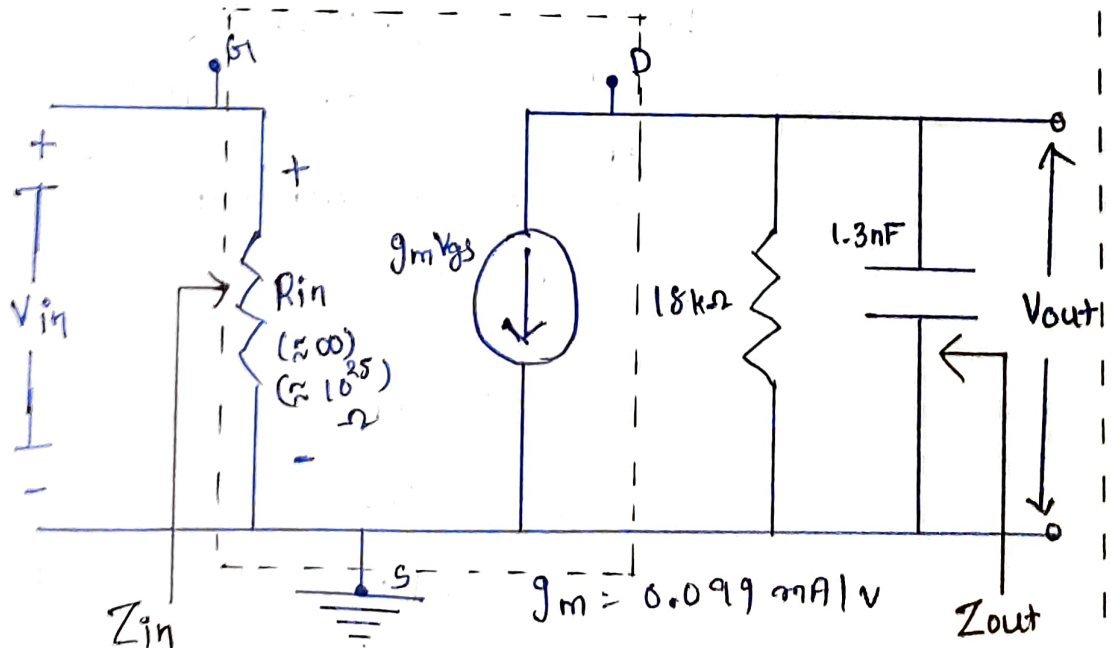
$$= -0.099 \times 18 \times 10^3 \times 10^{-3} \text{ V/V}$$

$$= -1.782$$

which is pretty close to simulated value.

Note:- Here channel length modulation is neglected because in 500 nm library provided, there is no mention of 'LAMBDA' (λ), so by considering default value of $LAMBDA = 0$, $r_o = \infty$.

* Small Signal Model :-



* R_{in} here will be non infinite for this model, its bode plot can be found here.

$$R_{out} = Z_{out} = R_o \parallel X_c$$

$$= \frac{(R_o) \left(\frac{1}{sC} \right)}{R_o + \frac{1}{sC}}$$

$$= \frac{R_o}{1 + sCR_o} \Omega$$

it has pole at $s = \frac{-1}{CR_o}$

$$|Z_{out}| = \frac{R_o}{\sqrt{1 + (\omega CR_o)^2}} = \frac{R_o}{\sqrt{1 + (\omega CR_o)^2}} \Omega$$

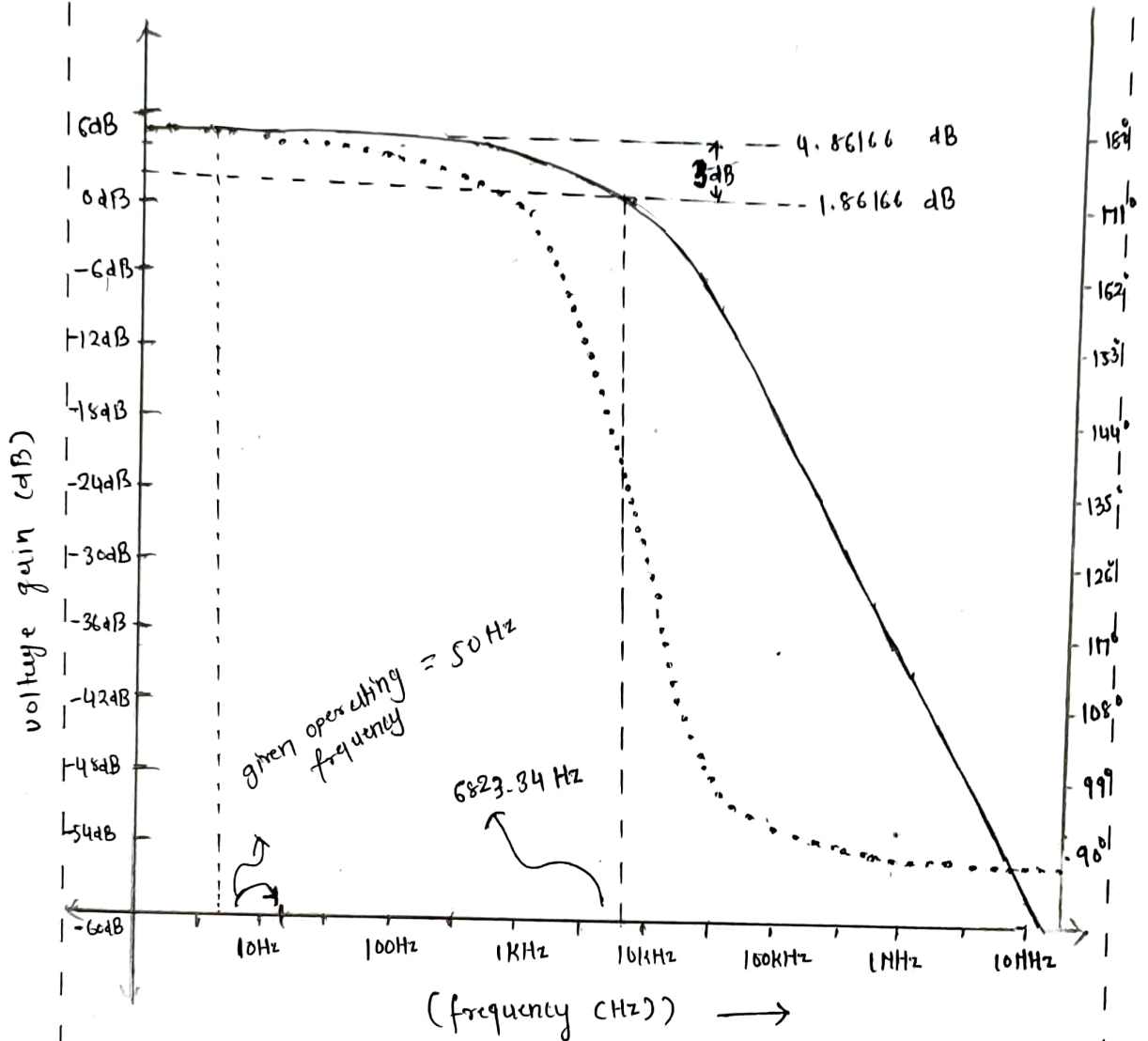
$$\angle Z_{out} = -\tan^{-1} \left(\frac{1}{\omega CR_o} \right)$$

$$|Z_{out}| \text{ at } 50 \text{ Hz (calculated)} = 17.99 \text{ k}\Omega$$

$$|Z_{out}| \text{ at } 50 \text{ Hz (simulated)} = 17.99 \text{ k}\Omega$$

From the simulation Z_{in} at 50 Hz is order of 10^3 , so in small signal analysis it can be estimated as open circuit.

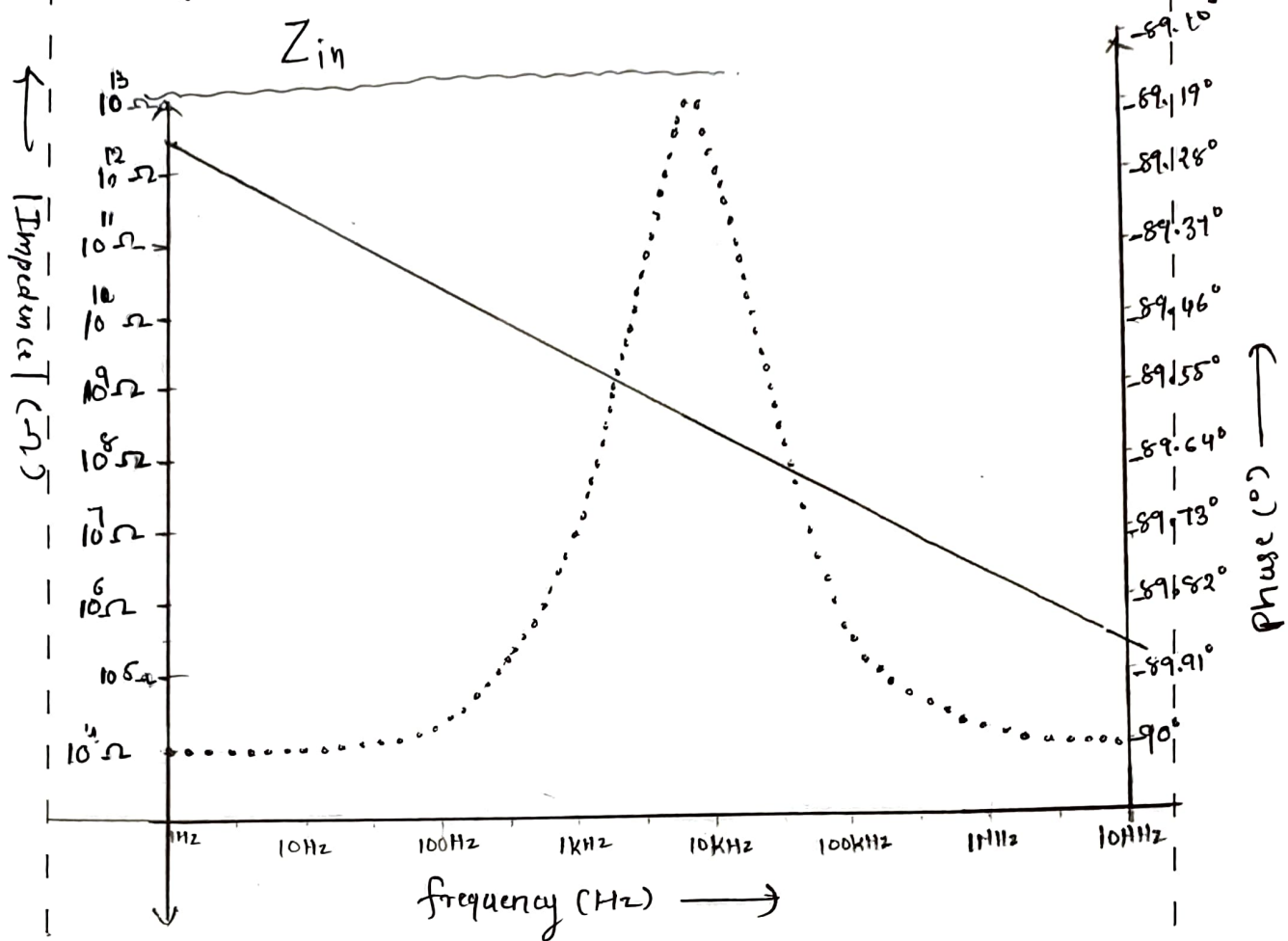
* Frequency Response



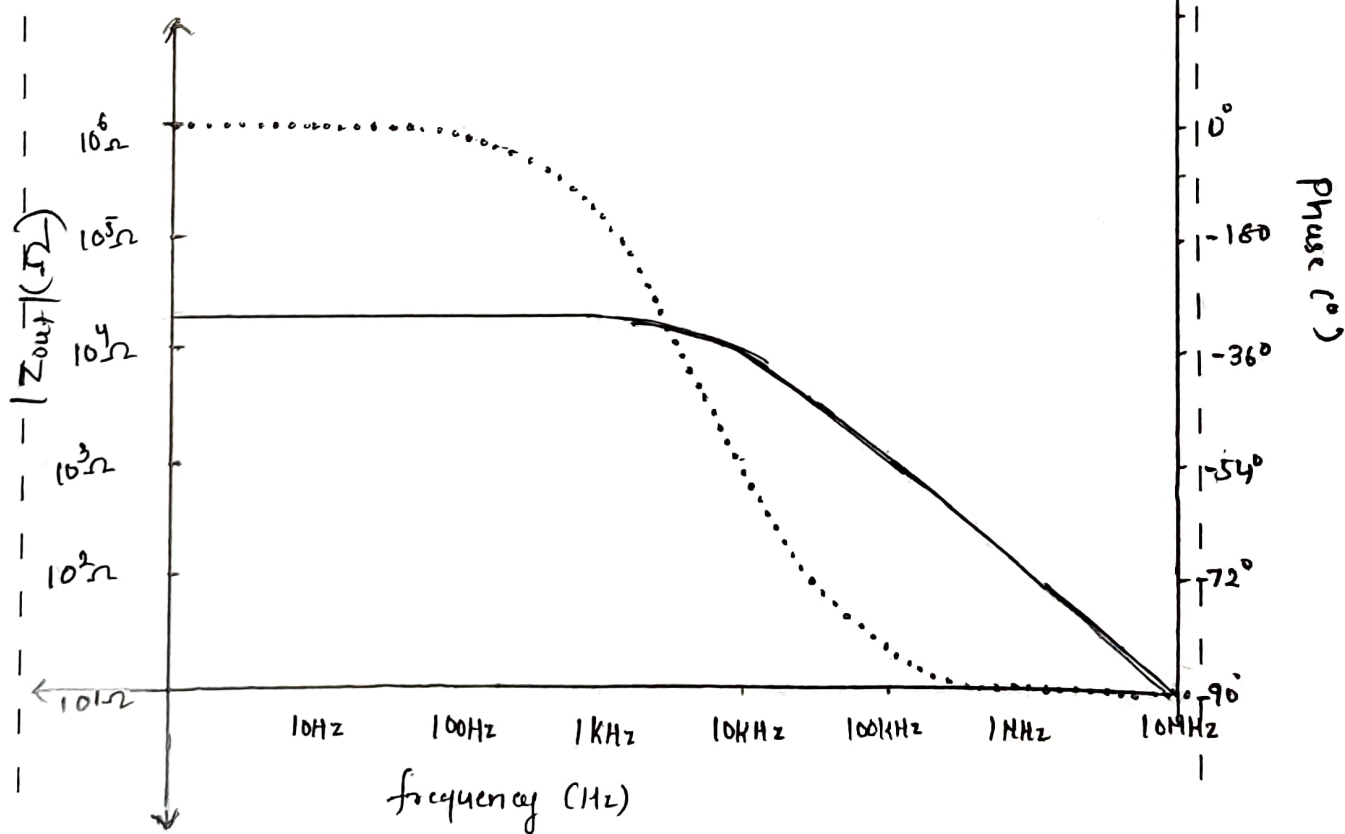
⇒ Here it can be seen that, gain decreases with increase in frequency, because R_{out} decreases with frequency so,

$$A_v = -g_m R_{out}, R_{out} \downarrow \Rightarrow A_v \downarrow$$

* Input Resistance (Impedance)



* Output Resistance (Impedance)



Question-1

1. Finding DC Operating Point/Transfer Characteristics

```
* DC operating point

.model NMOS NMOS
.model PMOS PMOS
.lib C:\Users\devan\Documents\LTspiceXVII\lib\cmp\standard.mos
.INCLUDE mue1.txt
M1 Vout in 0 0 NMOS
R1 N001 Vout 18k
V1 N001 0 5
C1 Vout 0 1.3n
V2 in 0 2.12688

.dc V2 0 10 0.0001
.backanno
.end
```

2. Finding Frequency Response

```
* Frequency Response
M1 Vout in 0 0 NMOS
R1 N001 Vout 18k
V1 N001 0 5
C1 Vout 0 1.3n
V2 in 0 2.12688 AC 1
.model NMOS NMOS
.model PMOS PMOS
.lib C:\Users\devan\Documents\LTspiceXVII\lib\cmp\standard.mos
.INCLUDE mue1.txt

.ac dec 1000 1 10Meg
.MEASUE AC vo FIND mag(V(vout)/V(in)*0.707945784) AT=1m
.MEASURE AC f FIND frequency WHEN mag(V(vout)/V(in))={mag(vo)}
.MEAS AC v1 FIND V(vout)/V(in) AT=50

.backanno
.end
```

3. Output Characteristics:

```
* Output Charecteristics
```

```
.model NMOS NMOS
.model PMOS PMOS
.lib C:\Users\devan\Documents\LTspiceXVII\lib\cmp\standard.mos
.INCLUDE mue1.txt
M1 Vout in 0 0 NMOS
R1 N001 Vout 18k
V1 N001 0 5
C1 Vout 0 1.3n
V2 in 0 2.12688

.dc V2 0 10 0.0001
.backanno
.end
```

4. Input Impedence:

```
* Frequency Response
M1 Vout in 0 0 NMOS
R1 N001 Vout 18k
V1 N001 0 5
C1 Vout 0 1.3n
V2 in 0 2.12688 AC 1
.model NMOS NMOS
.model PMOS PMOS
.lib C:\Users\devan\Documents\LTspiceXVII\lib\cmp\standard.mos
.INCLUDE mue1.txt

.ac dec 1000 1 10Meg

* Finding Input Impedence
* Now plot -V(in)/I(V2)

.backanno
.end
```

5. Output Impedence

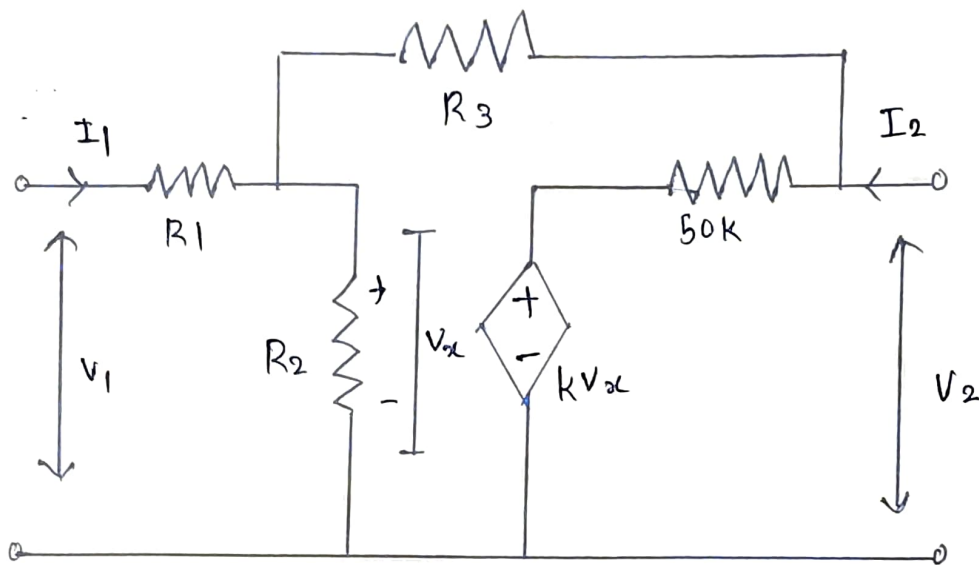
```
* C:\Users\devan\Documents\ASSNMNT1- FILES\Q1.asc
M1 Vout 0 0 0 NMOS
R1 N001 Vout 18k
V1 N001 0 5
C1 Vout 0 1.3n
V2 Vout 0 SINE(0) AC 1
.model NMOS NMOS
.model PMOS PMOS
.lib C:\Users\devan\Documents\LTspiceXVII\lib\cmp\standard.mos
.INCLUDE mue1.txt
.ac dec 1000 1 10Meg

* Finding Output Impedence
* Plot -V(vout)/I(V2)
```

```
.backanno  
.end
```

PROBLEM - 2

* Circuit Diagram:-



Here $R_1 = 55 \text{ k}\Omega$
 $R_2 = 45 \text{ k}\Omega$
 $R_3 = 80 \text{ k}\Omega$
 $k = 14$

} According to ID no. & Tut no.

* Finding Z parameters:-

↳ Equation of Z parameters

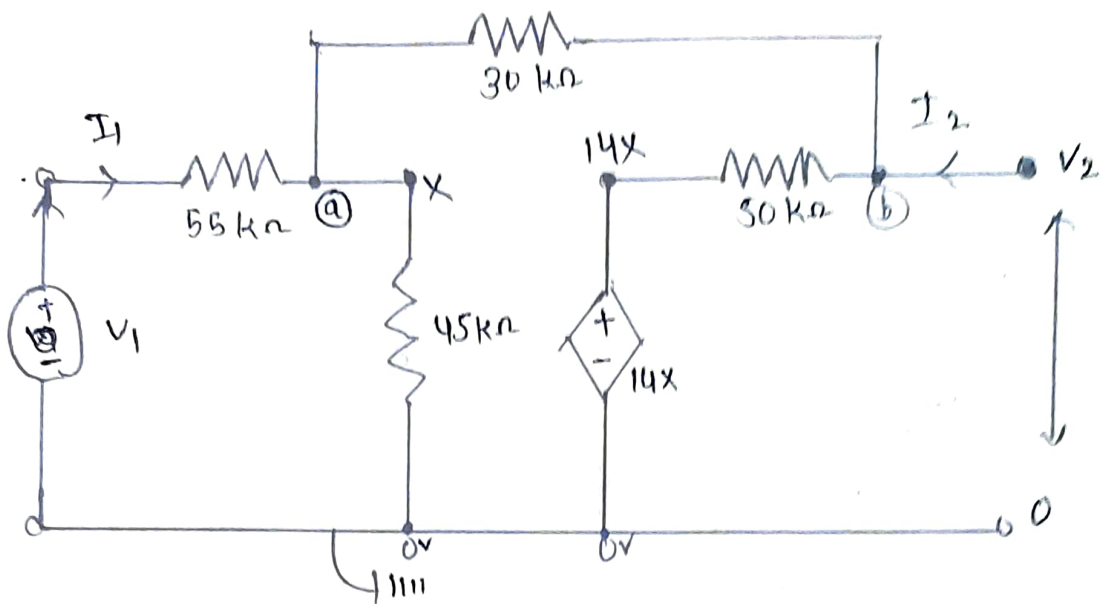
$$\begin{cases} V_1 = Z_{11}I_1 + Z_{12}I_2 \\ V_2 = Z_{21}I_1 + Z_{22}I_2 \end{cases}$$

↳ $V_1, V_2 \rightarrow$ dependent variable

↳ $I_1, I_2 \rightarrow$ independent variable.

(1) Finding Z_{11} & Z_{21} :-

↳ By applying voltage at input side and keeping open circuit at output port.



Writing KCL at (a),

$$I_1 = \frac{x}{45k} + \frac{x - V_2}{30k} \quad \text{--- (1)}$$

$$I_1 = \frac{V_1 - x}{55k} \quad \text{--- (2)}$$

From (1) and (2),

$$\frac{V_1 - x}{55k} = \frac{x}{45k} + \frac{x - V_2}{30k}$$

$$\Rightarrow \frac{V_1 - x}{11} = \frac{x}{9} + \frac{x - V_2}{6} \quad \text{--- (3)}$$

→ KCL at node (b)

$$\frac{V_2 - 14x}{50k} = \frac{x - V_2}{30k}$$

$$3V_2 - 42x = 5x - 5V_2$$

$$8V_2 = 47x$$

$$\boxed{x = \frac{8V_2}{47}}$$

Putting value of x in Eqⁿ (3)

$$V_1 - \frac{8V_2}{47} = \frac{8V_2}{47 \times 9} + \frac{\frac{8V_2}{47} - V_2}{6}$$

$$\frac{V_1}{11} = \frac{8V_2}{47 \times 11} + \frac{8V_2}{47 \times 9} - \frac{39V_2}{6 \times 47}$$

$$\boxed{V_1 = -1.1430 V_2} \quad \dots (5)$$

Putting value of (5) in (6)

$$I_1 = \frac{V_1 - \frac{8V_2}{47}}{55k}$$

$$I_1 = \frac{V_1 + \frac{8}{47} \left(\frac{V_1}{1.1430} \right)}{55k}$$

$$I_1 = \frac{V_1 \left(1 + \frac{8}{47 \times 1.1430} \right)}{55k}$$

$$\boxed{Z_{11} = \frac{V_1}{I_1} = 47.871 k\Omega}$$

Putting value of V_2 in (2)

$$I_2 = \frac{V_2}{Z_2} = 4\mu A$$

$$I_1 = \frac{-1.1430 V_2 - \frac{8V_2}{47}}{55k}$$

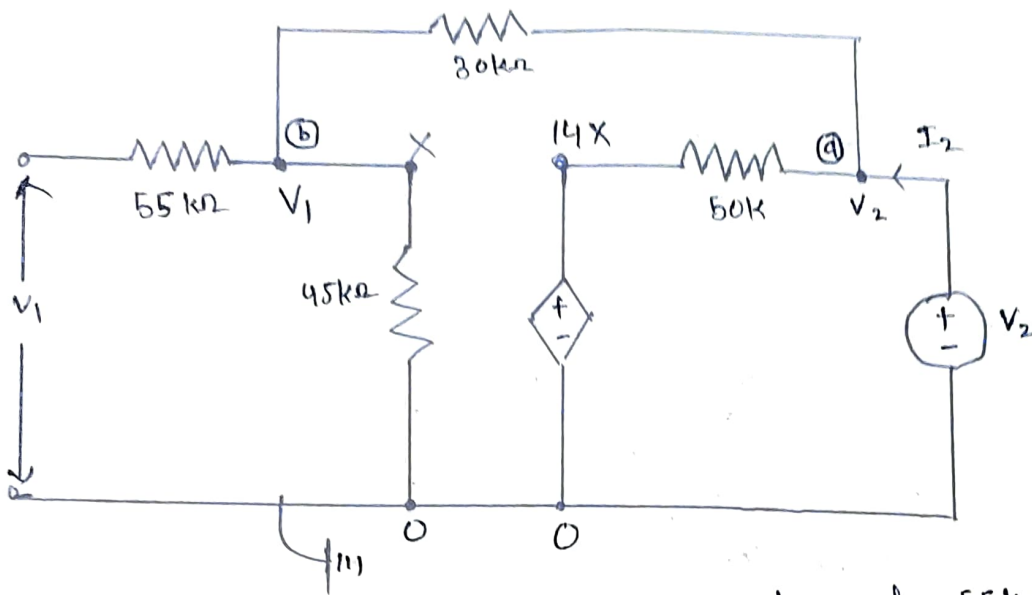
$$\boxed{Z_{21} = \frac{V_2}{I_1} = -410.882 k\Omega}$$

* Finding Z_{22} and Z_{12} :-

↳ By applying voltage at output port and keeping open circuit at input port.

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As there is no current passing through 55kΩ Resistor, $V_1 = X$

$$\frac{V_2 - X}{30k} = \frac{X - 0}{45k} \Rightarrow \frac{V_2 - X}{2} = \frac{X}{3}$$

$$3V_2 - 3X = 2X$$

$$\boxed{X = \frac{3V_2}{5}} \quad \text{--- (1)}$$

$$I_2 = \frac{V_2 - V_1}{30k} + \frac{V_2 - 14X}{50k}$$

$$= \frac{V_2 - X}{30k} + \frac{V_2 - 14X}{50k}$$

Using (1),

$$I_2 = \frac{V_2 - \frac{3V_2}{5}}{30k} + \frac{V_2 - 14 \cdot \frac{3V_2}{5}}{50k}$$

$$I_2 = V_2 \left(\frac{2}{5 \cdot 30k} - \frac{37}{5 \cdot 50k} \right)$$

$$I_2 = V_2 \times (-1.3467 \times 10^{-4})$$

$$Z_{22} = \frac{V_2}{I_2} = -7425.7425 \Omega$$

$$\boxed{Z_{22} = -7.425 \text{ k}\Omega}$$

$$V_1 = x$$

$$V_1 = \frac{3V_2}{5}$$

$$V_1 = \frac{3}{5} (-7.425 \times 10^3) \text{ I}_2$$

$$\frac{V_1}{\text{I}_2} = \frac{3}{5} \times (-7425.7425)$$

$$= -4455.44 \Omega$$

$$\boxed{Z_{12}} = \boxed{-4.455 \text{ k}\Omega}$$

$$\boxed{Z_{11} = 47.871 \text{ k}\Omega}$$

$$\boxed{Z_{12} = -4.455 \text{ k}\Omega}$$

$$\boxed{Z_{21} = -41.882 \text{ k}\Omega}$$

$$\boxed{Z_{22} = -7.425 \text{ k}\Omega}$$

From Z-parameter obtaining

[1] h-parameter of-

$$h_{11} = \frac{\Delta Z}{Z_{22}} = \frac{\begin{vmatrix} Z_{11} & Z_{12} \\ Z_{21} & Z_{22} \end{vmatrix}}{Z_{22}} = 72.99 \text{ k}\Omega$$

$$\boxed{h_{12}} = \frac{Z_{12}}{Z_{22}} = 0.6$$

$$\boxed{h_{21}} = \frac{-Z_{21}}{Z_{22}} = -5.6399$$

$$\boxed{h_{22}} = \frac{1}{Z_{22}} = -1.346 \times 10^{-4} \text{ S}$$

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[2] ABCD parameters

$$A = t_{11} = \frac{Z_{11}}{Z_{21}} = -1.14303$$

$$B = t_{12} = \frac{\Delta Z}{Z_{21}} = 12943.306 = 12.943 \text{ k}\Omega$$

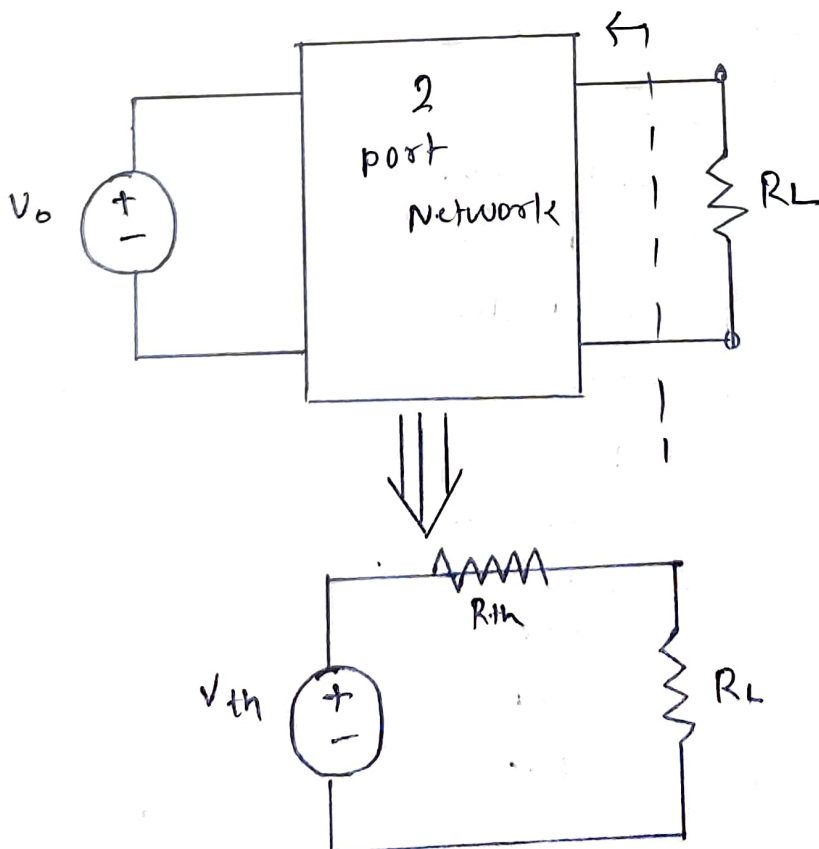
$$C = t_{21} = \frac{1}{Z_{21}} = -2.387 \times 10^{-5} \text{ S}$$

$$D = t_{22} = \frac{Z_{22}}{Z_{21}} = 0.1773$$

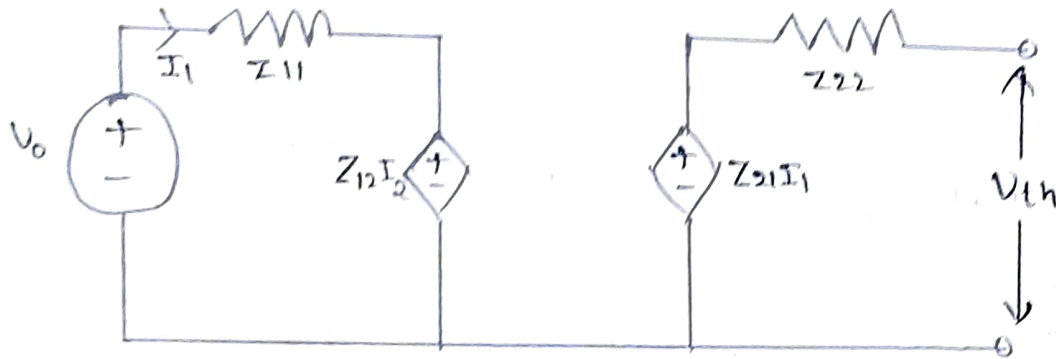
* Finding Load Resistance for max. power transfer:

→ In linear circuit, when $Z_{\text{load}} = Z_{\text{th}}^*$, max. power can be transferred.

→ we can find thevenin equivalent of 2-port network with input voltage supplied, about output port.



* Open circuiting output voltage. (P2)



Here $I_2 = 0$ as output side is open circuiting

$$\text{so, } V_{th} = Z_{21} I_1 \quad \text{--- (1)}$$

applying KVL at input side loop.

$$V_0 - Z_{11} I_1 - Z_{12} (0) = 0$$

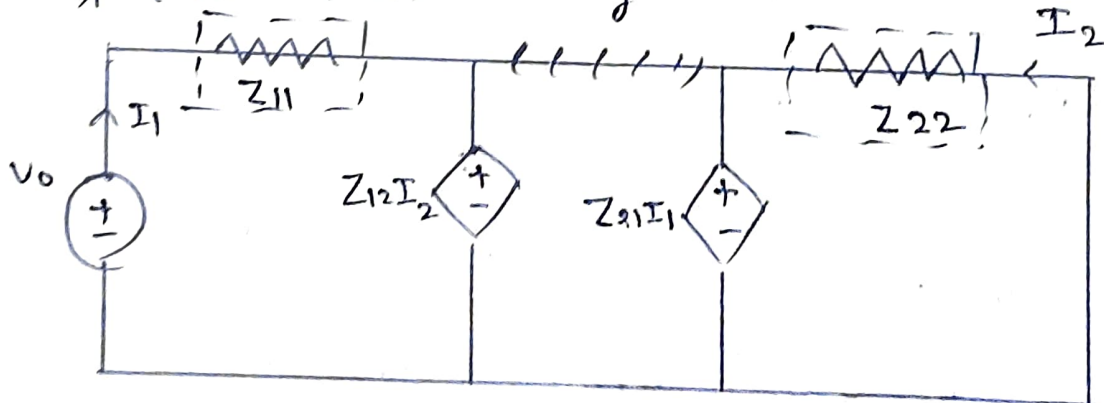
$$V_0 = Z_{11} I_1$$

$$\Rightarrow I_1 = \frac{V_0}{Z_{11}}$$

putting value of I_1 in (1)

$$V_{th} = \frac{Z_{21} V_0}{Z_{11}}$$

* Now short-circuiting output port.



Applying KVL in output side loop.

$$Z_{21}I_1 + Z_{22}I_2 = 0$$

$$I_1 = \frac{-Z_{22}I_2}{Z_{21}} \quad \text{--- (1)}$$

Applying KVL in input side loop.

$$V_0 - Z_{11}I_1 - Z_{12}I_2 = 0$$

$$V_0 - Z_{11}\left(\frac{-Z_{22}I_2}{Z_{21}}\right) - Z_{12}I_2 = 0$$

$$V_0 = Z_{12}I_2 - \frac{Z_{11}Z_{22}}{Z_{21}} \cdot I_2$$

$$V_0 = I_2 \left(\frac{Z_{12}Z_{21} - Z_{11}Z_{22}}{Z_{21}} \right)$$

$$I_{SC} = I_2 = V_0 \left(\frac{Z_{21}}{Z_{12}Z_{21} - Z_{11}Z_{22}} \right)$$

4)
Short circuit
current.

$$R_{th} = \frac{V_{th}(V_{oc})}{I_{sc}}$$

$$= \frac{Z_{21}(V_0)}{Z_{11}} \left(V_0 \left(\frac{Z_{21}}{Z_{12}Z_{21} - Z_{11}Z_{22}} \right) \right)$$

$$R_{th} = \frac{Z_{12}Z_{21} - Z_{11}Z_{22}}{Z_{11}}$$

When R_{load} becomes equal to R_{th} ,
Power across becomes maximum, according
to Maximum Power Transfer Equation.

Putting value of parameters

$$R_{in} = \frac{(-4.455k)(-41.882k) - (47.871k)(-7.425k)}{47.871k}$$

$$R_{in} = 11.322k\Omega$$

which is quite close to simulated
result $R_{in}|_{\text{simulated}} = 11.323k\Omega$

$$\Rightarrow R_{load} = 11.322k\Omega$$

* RESULTS:-

Z-Parameter	Calculated (k Ω)	Simulated (k Ω)
Z ₁₁	47.871 k Ω	47.871 k Ω
Z ₁₂	-4.455 k Ω	4.455 k Ω
Z ₂₁	-41.882 k Ω	-41.882 k Ω
Z ₂₂	-7.425 k Ω	-7.425 k Ω

h-parameter	Calculated	Simulated
h ₁₁	72.99 k Ω	72.99 k Ω
h ₁₂	0.6	0.6
h ₂₁	-5.6399	-5.64
h ₂₂	-1.346 $\times 10^{-4}$ S	-1.3467 $\times 10^{-4}$ S

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ABCD-Para.	Calculated	Simulated
A	-1.1403	-1.14032
B	12.943 k Ω	12.943 k Ω
C	-2.387 $\times 10^{-5}$ S	-2.3877 $\times 10^{-5}$ S
D	0.1773	0.177304

Load Resistance for max. power transfer

	Calculated	Simulated
R _{load}	11.322 k Ω	11.323 k Ω

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Question-2

1. Finding Z_{11} and Z_{21}

```
*Z11 and Z21

R1 N001 V1 55k
R2 0 N001 45k
R3 N002 V2 50k
R4 N001 V2 30k
E1 N002 0 N001 0 14
V1 V1 0 1
V2 NC_01 NC_02 V
. op
. backanno
. end
```

2. Finding Z_{12} and Z_{22}

```
* Z12 and Z22

R1 N001 V1 55k
R2 0 N001 45k
R3 N002 V2 50k
R4 N001 V2 30k
E1 N002 0 N001 0 14
V1 NC_01 NC_02 1
V2 V2 0 1
. op
. backanno
. end
```

3. Finding h_{11} and h_{21}

```
* h11 and h21

R1 N001 V1 55k
R2 0 N001 45k
R3 N002 V2 50k
R4 N001 V2 30k
E1 N002 0 N001 0 14
V1 V1 0 1
V2 V2 0 0
. op
. backanno
. end
```


4. Finding h_{12} and h_{22}

```
* h12 and h22

R1 N001 V1 55k
R2 0 N001 45k
R3 N002 V2 50k
R4 N001 V2 30k
E1 N002 0 N001 0 14
V1 NC_01 NC_02 1
V2 V2 0 1
. op
. backanno
. end
```

5. Finding **A** and **C** parameter

```
* A and C

R1 N001 V1 55k
R2 0 N001 45k
R3 N002 V2 50k
R4 N001 V2 30k
E1 N002 0 N001 0 14
V1 V1 0 1
V2 NC_01 NC_02 1
. op
. backanno
. end
```

6. Finding **B** and **D** Parameters

```
* B and D

R1 N001 V1 55k
R2 0 N001 45k
R3 N002 V2 50k
R4 N001 V2 30k
E1 N002 0 N001 0 14
V1 V1 0 1
V2 V2 0 0
. op
. backanno
. end
```